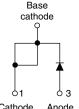




Schottky Rectifier, 20 A





TO-220AC	
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SYMBOL

I_{F(AV)}

 V_{RRM}

 I_{FSM}

 V_F

 $T_{\rm J}$

VOLTAGE RATINGS

Maximum DC reverse voltage

Maximum working peak reverse voltage

PARAMETER

Bas	e
catho	de
0	
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1	
	+
T	→
01	ბ 3
Cathode	Anode
Odinodo	7 111000

CHARACTERISTICS

SYMBOL

 V_R

 V_{RWM}

Rectangular waveform

19 A_{pk} , $T_J = 125$ °C (typical)

 $t_n = 5 \mu s sine$

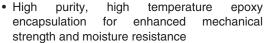
Range

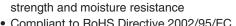
PRODUCT SUMMARY					
Package	TO-220AC				
I _{F(AV)}	20 A				
V _R	15 V				
V _F at I _F	See Electrical table				
I _{RM} max.	600 mA at 100 °C				
T _J max.	125 °C				
Diode variation	Single die				
E _{AS}	10 mJ				

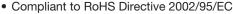
MAJOR RATINGS AND CHARACTERISTICS

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability







VALUES

20

15

700

0.25

- 55 to 125

VS-STPS20L15D-N3

15

- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)



VS-STPS20L15DPbF

15

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.





HALOGEN **FREE**

UNITS

٧

Α

٧

°C

UNITS

V

ABSOLUTE MAXIMUM RATINGS **PARAMETER** SYMBOL **TEST CONDITIONS VALUES** UNITS Maximum average forward current 50 % duty cycle, T_C = 85 °C, rectangular waveform I_{F(AV)} 20 Α See fig. 5 Maximum peak one cycle 5 μs sine or 3 μs rect. pulse Following any rated load 700 non-repetitive surge current condition and with rated I_{FSM} Α 10 ms sine or 6 ms rect. pulse V_{RRM} applied 330 See fig. 7 $T_J = 25$ °C, $I_{AS} = 2$ A, L = 6 mH Non-repetitive avalanche energy EAS 10 m.J Current decaying linearly to zero in 1 μs 2 Α Repetitive avalanche current I_{AR} Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical



VS-STPS20L15DPbF, VS-STPS20L15D-N3

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			UNITS
		19 A	T _{.1} = 25 °C	-	0.41	V
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	11 = 23 0	ı	0.52	
See fig. 1	V FM (1)	19 A	T 105 °C	0.25	0.33	
		40 A	- T _J = 125 °C	0.37	0.50	
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C		-	10	mA
See fig. 2		T _J = 100 °C	V _R = Rated V _R	-	600	IIIA
Threshold voltage	V _{F(TO)}	T. T. manimum		0.1	82	V
Forward slope resistance	r _t	$T_J = T_J \text{ maximum}$ 7.6		.6	mΩ	
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	-	2000	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 8			-	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µs				V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		- 55 to 125	°C	
Maximum storage temperature range	T _{Stg}		- 55 to 150		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4			
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D²PAK)	40		
Approximate weight			2	g	
Approximate weight			0.07	OZ.	
Mounting torque	n	Non-lubricated threads	6 (5)	kgf ⋅ cm	
Mounting torque maximum	n	Non-lubricated tilleads	12 (10)	(lbf ⋅ in)	
Marking device		Case style TO-220AC	STPS2	20L15D	

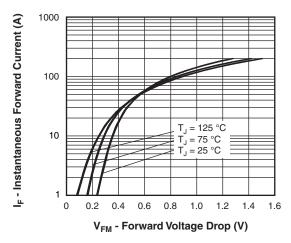


Fig. 1 - Maximum Forward Voltage Drop Characteristics

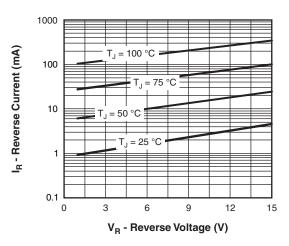


Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

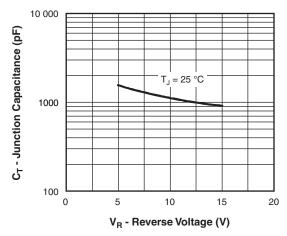


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

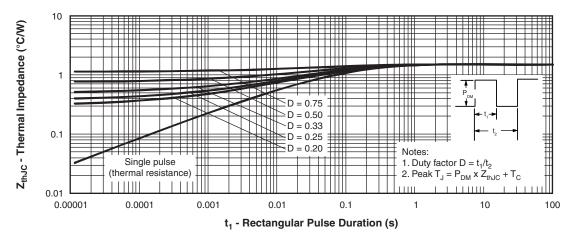


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

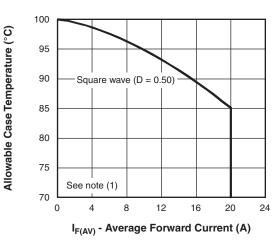


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

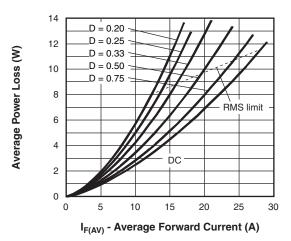


Fig. 6 - Forward Power Loss Characteristics

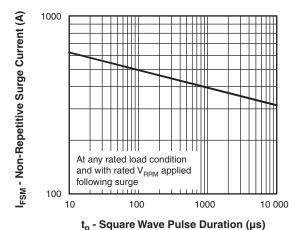


Fig. 7 - Maximum Non-Repetitive Surge Current

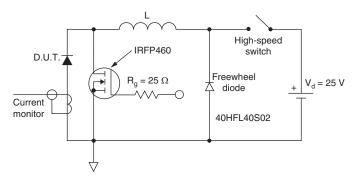


Fig. 8 - Unclamped Inductive Test Circuit

Note

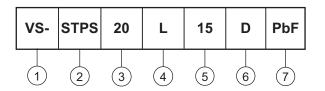
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

VS-STPS20L15DPbF, VS-STPS20L15D-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Schottky STPS series

Current rating (20 = 20 A)

4 - L = Low voltage drop

5 - Voltage rating (15 = 15 V)

D = Essential part number

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

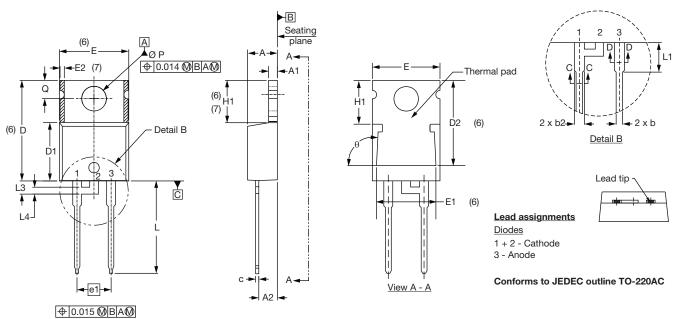
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-STPS20L15DPbF	50	1000	Antistatic plastic tube			
VS-STPS20L15D-N3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95221		
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224		
	TO-220AC -N3	www.vishay.com/doc?95068		
SPICE model		www.vishay.com/doc?95305		



TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIMETERS		INCHES		NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
E1	6.86	8.89	0.270	0.350	6	
E2	-	0.76	-	0.030	7	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6, 7	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
L3	1.78	2.13	0.070	0.084		
L4	0.76	1.27	0.030	0.050	2	
ØΡ	3.54	3.73	0.139	0.147		
Q	2.60	3.00	0.102	0.118		
θ	90° t	o 93°	90° t	o 93°		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

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Vishay

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